Supporting Information

Core-Expanded Naphthalene Diimides Fused with 2-(1,3-Dithiol-2-Ylidene)Malonitrile Groups for High-Performance, Ambient-Stable, Solution-Processed n-Channel Organic Thin Film Transistors

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Experimental Section

Materials and General Methods.

Chemicals were purchased from Aldrich, Alfa Aesar and used as received. Solvents and other common reagents were obtained from the Sinopharm Chemical Reagent Co., (TBNDA),¹ Ltd. 2,3,6,7-Tetrabromonaphthalene dianhydride 2-decyl-teradecylamine,² 2-octyl-dodecylamine,³ and sodium 1,1-dicyanoethylene-2,2-dithiolate⁴ were synthesized according to the reported procedures. ¹H-NMR (300 MHz) and ¹³C-NMR (100 MHz) spectra were measured in CDCl₃ on Varian Mercury (300 MHz or 400 MHz) instruments, using tetramethylsilane as an internal standard. Mass spectra (MALDI-TOF) were carried out on a Voyager-DE STR Mass Spectrometer. Elemental analyses were performed on an Elementar Vario EL III elemental analyzer. FT-IR spectra were determined using a Bio-Rad FTS-185 spectrometer. Electronic absorption spectra were measured on a Jasco V570 UV-vis spectrophotometer. TGA measurements were carried out on a TA Q500 instruments under a dry nitrogen flow at a heating rate of 10 °C/min, heating from room temperature to 500°C. DSC analyses were performed on a Perkin Elmer Pyris 1 instruments under a dry N₂ flow at a heating rate of 10 °C/min, heating from room temperature to 300 °C. Cyclic voltammetric measurements were carried out in a conventional three-electrode cell using a platinum button working electrode of 2 mm diameter, a platinum wire counter electrode, and a SCE reference electrode on a computer-controlled CHI610D instruments. X-ray diffraction (XRD) measurements were carried out in the reflection mode using a 2-kW Rigaku X-ray diffraction system. AFM was recorded on a Nanoscope IIIa atomic force microscopy (AFM) in trapping mode.

Synthetic Details

Synthesis of compounds 3 and 4.

Br
$$\frac{1) \text{ CH}_3\text{COOH, RNH}_2, \text{ reflux}}{2) \text{ PBr}_3, \text{ toluene, reflux}}$$
 $R = R$

TBNDA

2-decyl-tetracosyl 3

2-octyl-dodecyl 4

Scheme S1

Safety precautions should be cautioned for the synthesis of 2,3,6,7-Tetrabromonaphthalene dianhydride (TBNDA).¹.

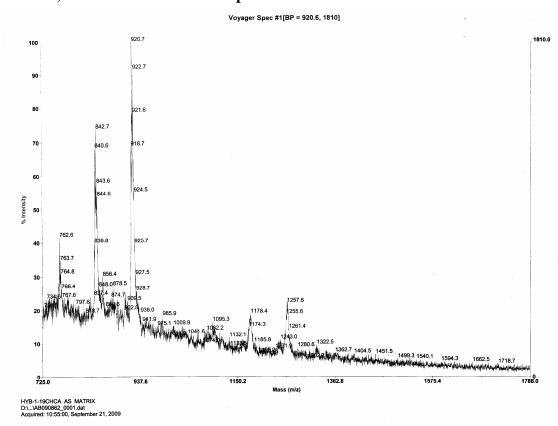
Safety Precautions: During the reaction, the glass water-cooled condenser could be blocked by solid SO₃. To give off bromine hydride, the blocked condenser should be continuously replaced. Plugging of the blocked condenser using flinty tools is forbidden (when the condenser was broken, the water will flow into the boiling oleum, and this is very dangerous).

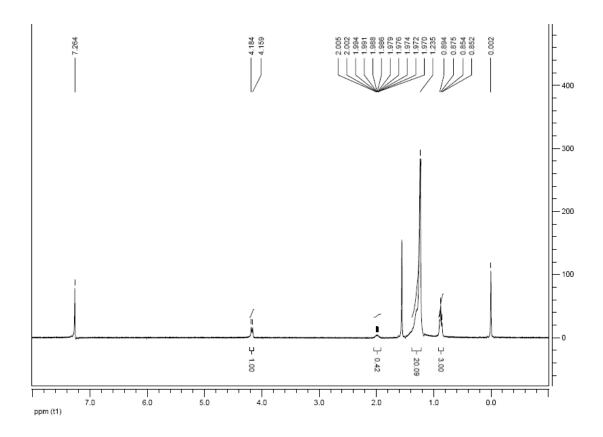
Although some mild and/or time-saving syntheses of TBNDA have been recently reported,⁵⁻⁷ our synthetic method for TBNDA can afford product with higher yield (96%) and higher purity.¹

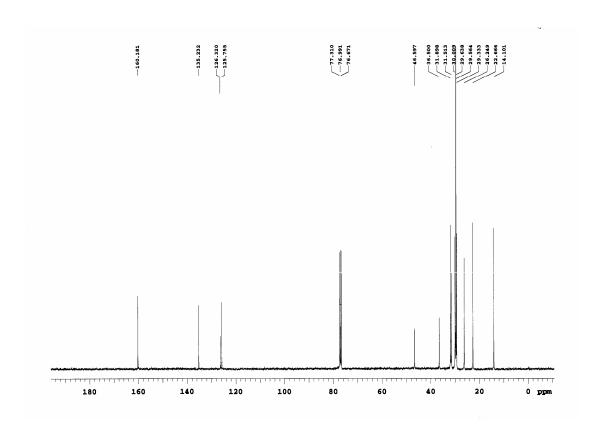
4,5,9,10-tetrabromo-2,7-bis(2-decyltetradecyl)benzo[lmn][3,8]phenanthroline-1,3,6,8(2H,7H)-tetraone (3)

As shown in Scheme S1, compound **3** was prepared from 2-decylt-etradecylamine² and TBNDA¹ according to the published procedure for the synthesis of 4,5,9,10-Tetrabromo-2,7-dioctyl-benzo[lmn][3,8]phenanthroline-1,3,6,8-tetraone.¹ **3** was obtained as a yellow solid in 19% yield (calculated from TBNDA): MS (MALDI-TOF) m/z 1257.6 (M⁺); ¹H-NMR (300 MHz, CDCl₃) δ (ppm): 0.852–0.894 (m, 6H, –CH₃), 1.287–1.409 (m, 8H, CH₂), 1.235 (b, 40H, CH₂), 1.970-2.005 (m, 1H, CH), 4.159–4.184 (d, J = 7.50 Hz, 2H, –CH₂–N); ¹³C-NMR (100 MHz, CDCl₃): δ 14.10, 22.67, 26.25, 29.33, 29.56, 29.64, 30.01, 31.50, 31.90, 36.50, 46.60, 125.75, 126.32, 135.23, 160.18 (CO).

The MS, ¹H-NMR and ¹³C-NMR spectra of 3 are listed as follows:



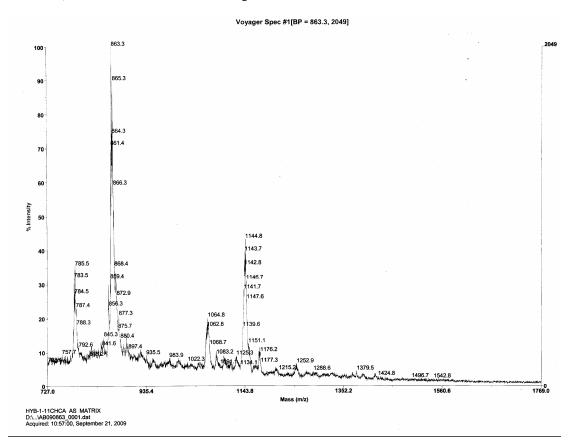


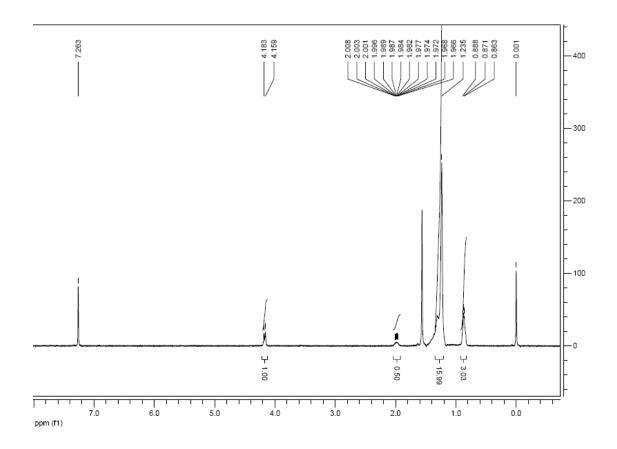


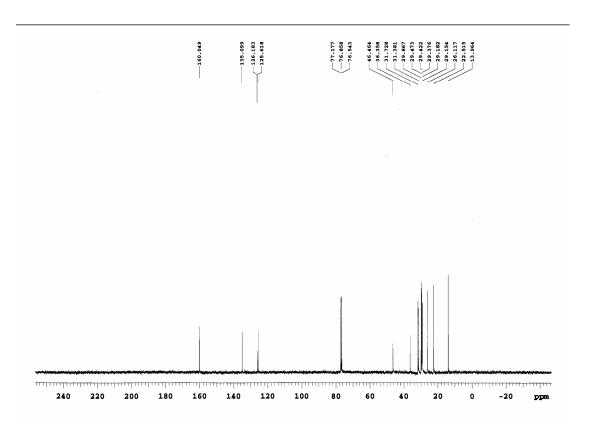
4,5,9,10-tetrabromo-2,7-bis(2-octyldodecyl)benzo[lmn][3,8]phenanthroline-1,3,6, 8(2H,7H)-tetraone (4)

As shown in Scheme S1, compound **4** was prepared from 2-octyl-dodecylamine³ and TBNDA¹ according to the published procedure for the synthesis of 4,5,9,10-Tetrabromo-2,7-dioctyl-benzo[lmn][3,8]phenanthroline-1,3,6,8-tetraone.¹ **4** was obtained as a yellow solid in 33% yield (calculated from TBNDA): MS (MALDI-TOF) m/z 1144.8 (M⁺); ¹H-NMR (300 MHz, CDCl₃) δ (ppm): 0.863–0.888 (m, 6H, -CH₃), 1.235 (b, 32H, CH₂), 1.966-2.008 (m, 1H, CH), 4.159–4.183 (d, J = 7.20 Hz, 2H, -CH₂–N); ¹³C-NMR (100 MHz, CDCl₃): δ 13.96, 22.52, 26.12, 29.15, 29.18, 29.38, 29.42, 29.87, 31.38, 31.73, 36.36, 46.46, 125.62, 126.18, 135.10, 160.05 (CO).

The MS, ¹H-NMR and ¹³C-NMR spectra of 4 are listed as follows:







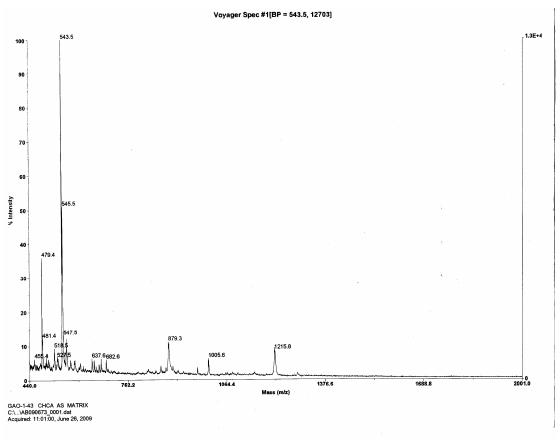
Synthesis of compounds 1 and 2.

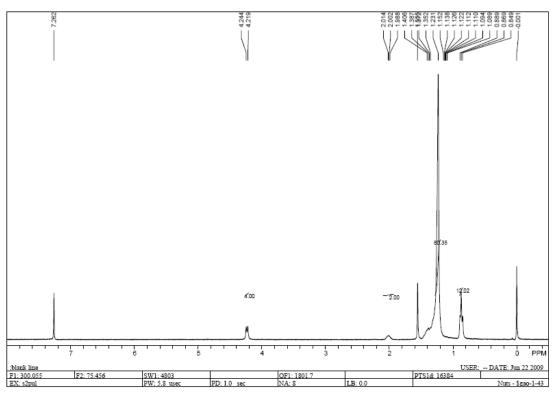
Scheme S2

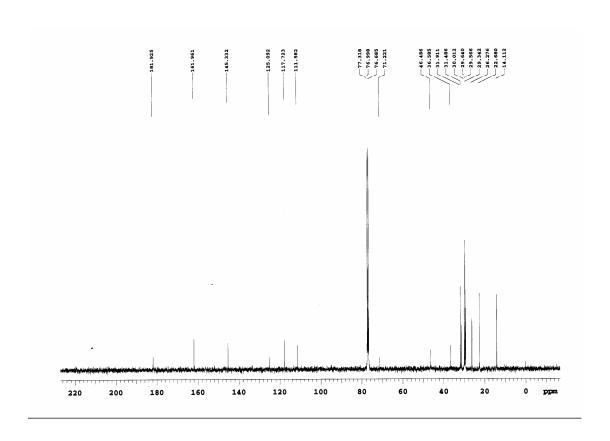
N,N'-bis(2-decyltetradecyl)-2,2'-Naphtho[2,3-d:6,7-d']bis[1,3]dithiol-2,7-diyliden e-bismalononitrile-1,4,5,8-tetracarbonyl diimide (1)

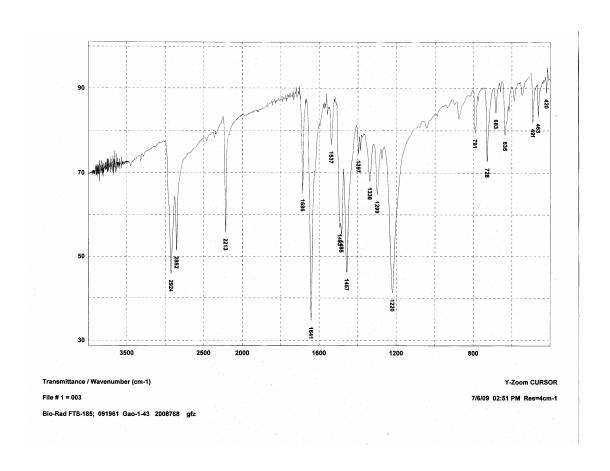
Under a nitrogen atmosphere, a solution of **3** (126 mg, 0.1 mmol) and sodium 1,1-dicyanoethylene-2,2-dithiolate⁴ (56 mg, 0.3 mmol) in THF (20 mL) was stirred at 50 °C for 1 hour. The mixture was cooled to room temperature and the solvent was removed under reduced pressure. Chromatography of the residue on a silica gel column with CH₂Cl₂/petroleum ether (3/1) as eluent afforded 60 mg (50 %) of **1** as a brownish red solid: Mp: 240 °C (from DSC); MS (MALDI-TOF) m/z 1215.8 (M⁺); ¹H-NMR (300 MHz, CDCl₃) δ (ppm): 0.849–0.889 (m, 6H, –CH₃), 1.231 (b, 40H, CH₂), 1.988-2.014 (m, 1H, CH), 4.219–4.244 (d, J = 7.50 Hz, 2H, –CH₂–N); ¹³C-NMR (100 MHz, CDCl₃): δ 14.11, 22.68, 26.28, 29.34, 29.57, 29.64, 30.01, 31.49, 31.91, 36.59, 46.49, 71.22 (=C(CN)₂), 111.58, 111.72 (C=N), 125.09, 145.33, 161.96 (C=O), 181.93 (=CS₂).; FT-IR (KBr, cm⁻¹) ν 2924 (s), 2852, 2213 (C=N), 1686, 1641 (vs), 1537, 1493, 1485, 1457 (s), 1397, 1338, 1299, 1220 (s), 791, 728, 683, 635, 491, 463.; Anal. Calcd. for C₇₀H₉₈N₆O₄S₄: C, 69.15; H, 8.12; N, 6.91. Found: C, 69.41; H, 8.37; N, 6.67.

The MS, ¹H-NMR, ¹³C-NMR and IR spectra of 1 are listed as follows:





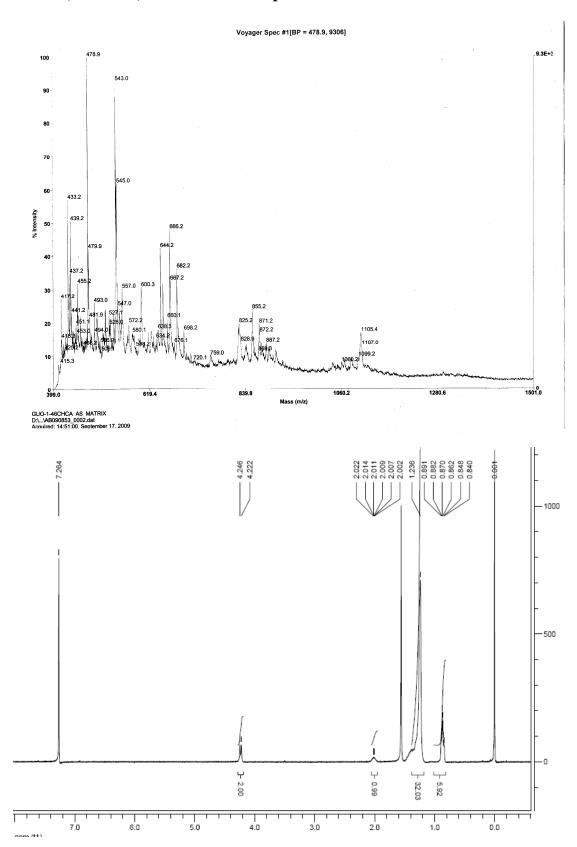


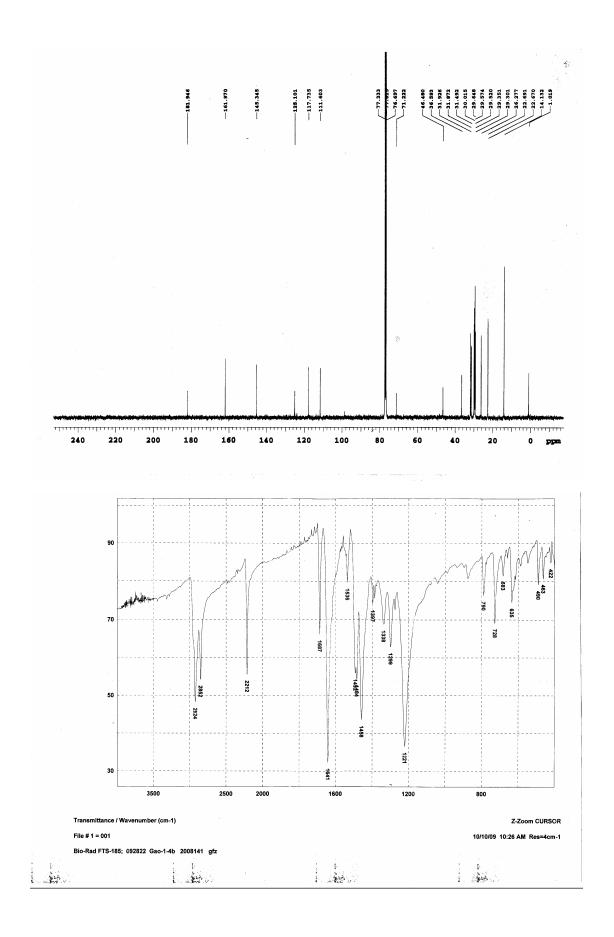


N,N'-bis(2-octyldodecyl)-2,2'-Naphtho[2,3-d:6,7-d']bis[1,3]dithiol-2,7-diylidene-b ismalononitrile-1,4,5,8-tetracarbonyl diimide (2)

A mixture of **4** (343 mg, 0.3 mmol), sodium 1,1-dicyanoethylene-2,2-dithiolate⁴ (168 mg, 0.9 mmol) and THF (50 mL) was stirred at 50 °C for 1 hour under a nitrogen atmosphere, then cooled to room temperature. After removing the solvent under reduced pressure, the residues were separated via column chromatography (silica gel, CH₂Cl₂/petroleum ether (2/1)). **2** (175 mg) was obtained as a purple solid with the yield of 53%: Mp: 265 °C (from DSC); MS (MALDI-TOF) *m/z* 1105.4 (M⁺); ¹H-NMR (300 MHz, CDCl₃) δ (ppm): 0.840–0.891 (m, 6H, –CH₃), 1.236 (b, 32H, CH₂), 2.002-2.022 (m, 1H, CH), 4.222–4.246 (d, J = 7.20 Hz, 2H, –CH₂–N); ¹³C-NMR (100 MHz, CDCl₃): δ 14.13, 22.67, 22.69, 26.28, 29.30, 29.35, 29.52, 29.57, 29.65, 30.02, 31.49, 31.87, 31.93, 36.59, 46.48, 71.22 (=C(CN)₂), 111.60, 111.74 (C≡N), 125.10, 145.35, 161.97 (C=O), 181.95 (=CS₂).; FT-IR (KBr, cm⁻¹) *v* 2924 (s), 2852, 2212 (C≡N), 1687, 1641 (vs), 1536, 1492, 1484, 1458 (s), 1397, 1338, 1299, 1221 (vs), 790, 728, 683, 635, 490, 463.; Anal. Calcd. for C₆₂H₈₂N₆O₄S₄: C, 67.48; H, 7.49; N, 7.62. Found: C, 67.38; H, 7.58; N, 7.56.

The MS, ¹H-NMR, ¹³C-NMR and IR spectra of 2 are listed as follows:





References

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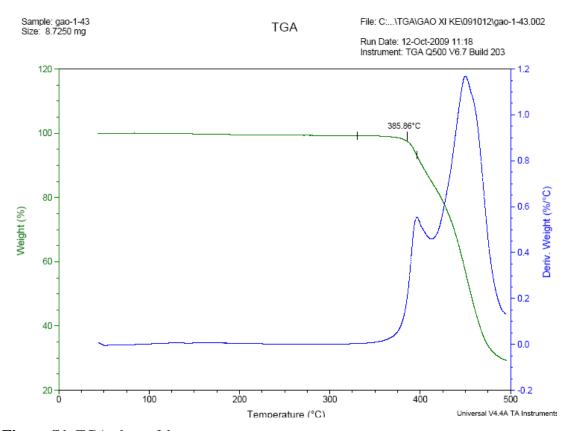


Figure S1. TGA plots of 1.

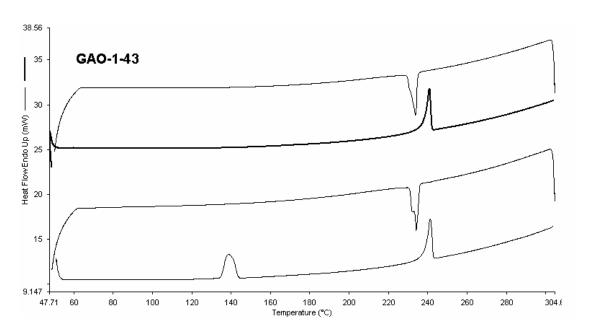


Figure S2. DSC spectra of **1**, in which the bottom spectrum is the first heating-cooling cycle and the top one is the second heating-cooling cycle.

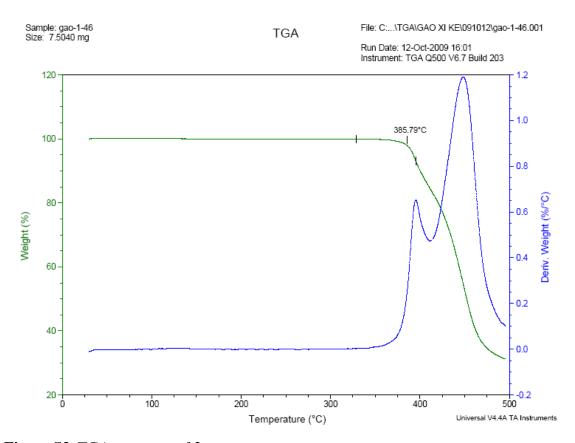


Figure S3. TGA spectrum of 2.

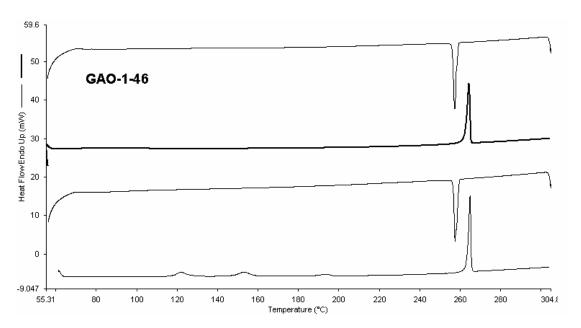


Figure S4. DSC spectra of **2**, in which the bottom spectrum is the first heating-cooling cycle and the top one is the second heating-cooling cycle.

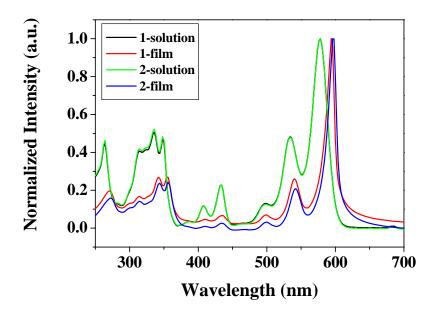


Figure. S5 Electronic absorption spectra of **1** (black, in CH_2Cl_2 ; red, as-spun film) and **2** (green, in CH_2Cl_2 ; blue, as-spun film).

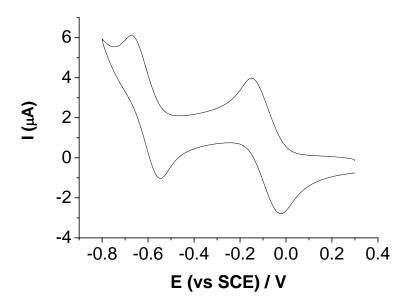


Figure. S6 Cyclic voltammogram of **1** (0.001 mol/L in CH_2Cl_2 , 0.1mol/L Bu_4NPF_6 , scan rate 50 mV/s)

OTFT Device Fabrication and Measurements

An n-type heavily doped Si wafer with a SiO₂ layer of 300 nm and a capacitance of 11 nF cm⁻² was used as the gate leectrode and dielectric layer. The thin films (40–60 nm) of **1** and **2** were deposited on octadecyltrichlorosilane (OTS)-treated SiO₂/Si substrates by spin-coating of their CHCl₃ solutions (10 mg/mL). Next, the thin films were annealed at 120 °C, 160 °C, or 180 °C. Gold (or silver) source and drain contacts (30 nm in thickness) were deposited by vacuum evaporation on the organic layer through a shadow mask, affording a bottom-gate top-contact device configuration. The channel length (*L*) and width (*W*) were 50 µm and 3 mm, respectively. Electrical measurements of OTFT devices were carried out at room temperature in air using a Keithley 4200 semiconductor parameter analyzer. The mobilities were determined in the saturation regime by using the equation $I_{DS} = (\mu W C_i/2L)(V_G - V_T)^2$, where I_{DS} is the drain-source current, μ is the field-effect mobility, *W* is the channel width, *L* is the channel length, C_i is the capacitance per unit area of the gate dielectric layer, and V_T is the threshold voltage.

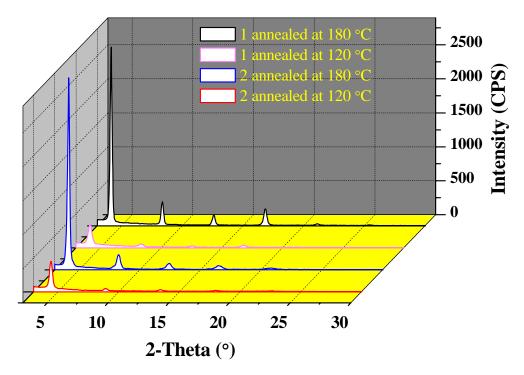


Figure S7. XRD patterns of spin-coated thin films of **1** and **2** annealed at 120 and 180°C.

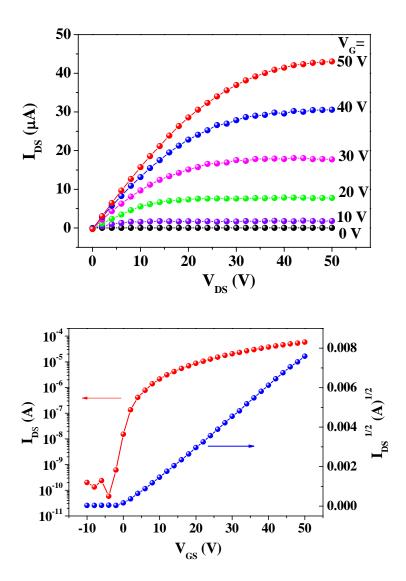


Figure S8. The output (top) and transfer (bottom) characteristics of an Au-contact OTFT device based on **1** (annealed at 160 °C), with $\mu_e = 0.16 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$, $I_{\text{on}}/I_{\text{off}} = 10^6$ and $V_{\text{T}} = 2 \text{ V}$ ($V_{\text{DS}} = 60 \text{ V}$).

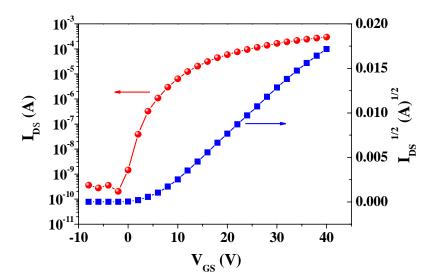


Figure S9. The transfer plots of an Ag-contact OTFT devices based on **2** (annealed at 180 °C), which affords the highest electron mobility of 0.51 cm²V⁻¹s⁻¹ with $I_{on}/I_{off} = 10^6$ and $V_T = 5.2$ V ($V_{DS} = 60$ V, scanning region of V_{GS} is -10 V~40 V).

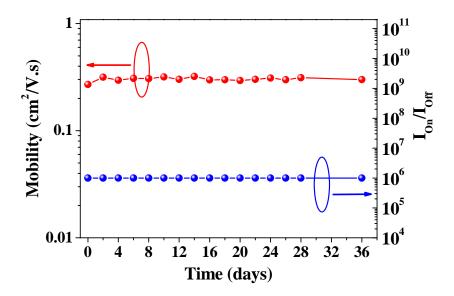


Figure S10. Air-stability measurements of an Au-contact OTFT device based on **2** (annealed at 180 °C) over a period of 36 days. Top: charge carrier mobilities as a function of time. Bottom: on/off ratios as a function of time.

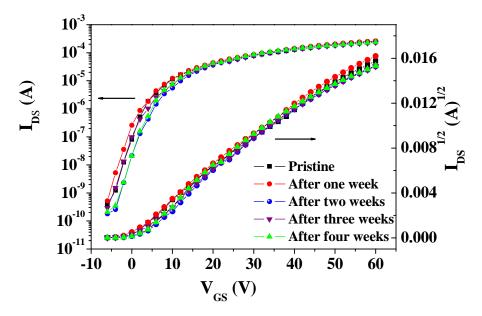


Figure S11. The transfer plots of the same OTFT device based on **2** (Figure S10), tested weekly during a period of four weeks under ambient conditions.

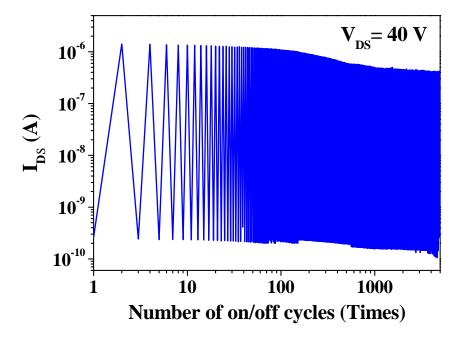


Figure S12: Electrical characteristics of a **2**-based OTFT during cycle-test in air (5000 times, between $V_{GS} = 0$ V (off) and $V_{GS} = 40$ V (on)).